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GaAs MMIC XM2400LB-PM0601

LNA / Drv. Amp. MMIC for 2.4GHz Wireless Communications

Applications

Low noise amplifier / Driver amplifier for 2.4GHz WLAN / Bluetooth[™] and other ISM2400 applications.

Features

1 Positive Supply Voltage	+3V
Internal Input and Output Matching Circuit	
Low Power Consumption	3V/4.5mA
High Gain	.G=15.5dB
Low Noise Figure	.F=1.9dB
High 1dB Compression Point	P1dB=4.0dBm
Small Plastic Package	. 6 pin Mini Mold Package (SOT-23-6)



Absolute Maximum Ratings

Symbol	Parameter	Conditions	Rating	Unit
Vdd	Supply Voltage	Ta = 25°C	5	V
Pin	RF Input Power	Ta = 25°C	-5	dBm
Тор	Operating Temperature	-	-20 ~ 85	°C
Tstg	Storage Temperature	-	-55 ~ 150	°C

Electrical Specifications

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
f0	Operation Frequency	-	2.4	-	2.5	GHz
Vdd	Supply Voltage (Drain)	-	-	3.0	-	V
IDD	Current Consumption	-	-	4.5	-	mA
G	Small Signal Gain		-	15.5	-	dB
F	Noise Figure	VDD = 3.0V	-	1.9	-	dB
VSWRin	Input VSWR	20 - 5022 Pin = -30dBm	-	1.8	-	-
VSWRout	Output VSWR		-	1.8	-	-
IP3	3rd Order Intercept Point	-	-	14.0	-	dBm
P1dB	1dB Compression Point	_	_	4.0	-	dBm

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■ Package Outline and Pin Connections



Pin No.	Function
1	RF Input
2	Not Connected
3	Vdd
4	RF Output
5	GND
6	GND

Land Pattern



All tolerances would be 0.03.

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Evaluation Board 1 (for High Gain)



Part No.	Value		
C1	GRM39	20pF (Murata)	
C2	GRM39	200pF (Murata)	

Substrate

Glass-epoxy Thickness = 0.2mm Metal Thickness = 18μm

Er = 4.2

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Typical Performance



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■ Evaluation Board 2 (for Better VSWR)



Symbol	Parameter	Conditions	Тур.	Unit
Idd	Current Consumption	-	4.5	mA
G	Small Signal Gain		15.0	dB
F	Noise Figure	$V_{DD} = 3.0V$	1.9	dB
VSWRin	Input VSWR	20 = 5002 Pin = -30dBm	1.6	-
VSWRout	Output VSWR		1.6	-
IP3	3rd Order Intercept Point	-	14.0	dBm
P1dB	1dB Compression Point	_	4.0	dBm

Part No.	Value		
C1	GRM39	20pF (Murata)	
C2	GRM39	470pF (Murata)	

Substrate Glass-epoxy

Thickness = 0.2mm

Metal Thickness = 18µm

Er = 4.2

Evaluation Board 3 (for Smaller Size)



Symbol	Parameter	Conditions	Тур.	Unit
IDD	Current Consumption	-	4.5	mA
G	Small Signal Gain		15.7	dB
F	Noise Figure	VDD = 3.0V	1.9	dB
VSWRin	Input VSWR	20 = 3002 Pin = -30dBm	1.8	-
VSWRout	Output VSWR	i ili oodbiii	1.9	-
IP3	3rd Order Intercept Point	-	14.0	dBm
P1dB	1dB Compression Point	-	4.0	dBm

Part No.		Value
С	GRM36	5.6pF (Murata)
L	LQP10	6.8nH (Murata)

Substrate

Glass-epoxy Thickness = 0.2mm Metal Thickness = 18μm

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